

2SK3309(TE24L,Q)

2SK3309(TE24L,Q) Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2SK3309(TE24L,Q) Specifications

Manufacturer Part Number	2SK3309(TE24L,Q)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-252-3, DPak (2 Leads + Tab), SC-63
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	450V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	10 V
Vgs(th) (Max) @ Id	5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	920pF @ 10V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	65W (Tc)
Rds On (Max) @ Id, Vgs	650 mOhm @ 5A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-220SM
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
	Report errors?

2SK3309(TE24L,Q) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

2SK3309(TE24L,Q) Payment Methods





If you have any question about 2SK3309(TE24L,Q), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com